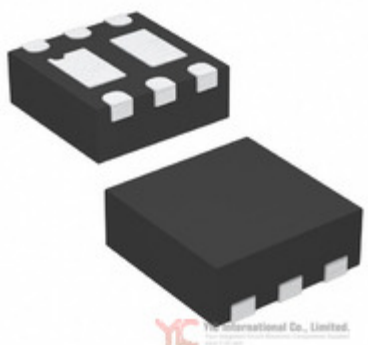

	<h2 style="color: #E67E22;">SIA907EDJT-T1-GE3</h2>
 <p>Image may be representation. See specs for product details.</p>	<b>Hersteller-Teilenummer:</b> SIA907EDJT-T1-GE3
	<b>Hersteller / Marke:</b> Electro-Films (EFI) / Vishay
	<b>Teil der Beschreibung:</b> MOSFET 2P-CH 20V 4.5A SC-70-6L
	<b>Datenblätter:</b>  SIA907EDJT-T1-GE3.pdf
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 12200 pcs Stock Available.
	<b>Liefern von:</b> Hong Kong
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	

### Spezifikationen

Teilenummer	SIA907EDJT-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET 2P-CH 20V 4.5A SC-70-6L
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	12200 pcs Stock
detaillierte Beschreibung	Mosfet Array 2 P-Channel (Dual) 20V 4.5A (Tc) 7.8W
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	7.8W
Verpackung / Gehäuse	PowerPAK® SC-70-6 Dual
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Dual
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.5A (Tc)
Rds On (Max) @ Id, Vgs	57 mOhm @ 3.6A, 4.5V
VGS (th) (Max) @ Id	1.4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SIA907EDJT-T1-GE3-ND

SIA907EDJT-T1-GE3 ist neu im Original, Suche SIA907EDJT-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIA907EDJT-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SIA907EDJT-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>SIA911ADJ-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 4.5A SC70-6</p>	 <p><b>SIA907EDJT</b> VISHAY SIA907EDJT VISHAY</p>	 <p><b>SIA907EDJT-T1-GE3</b> Vishay / Siliconix MOSFET 2P-CH 20V 4.5A SC-70-6L</p>	 <p><b>SIA907EDJT-T4-GE3</b> VISHAY SIA907EDJT-T4-GE3 VISHAY</p>
 <p><b>SIA911ADJ-T1-GE3</b> Vishay / Siliconix MOSFET 2P-CH 20V 4.5A SC70-6</p>	 <p><b>SIA906EDJ-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 4.5A SC70-6</p>	 <p><b>SIA906EDJ-T4-GE3</b> VISHAY SIA906EDJ-T4-GE3 VISHAY</p>	 <p><b>SIA910EDJ-T1-GE3</b> Vishay / Siliconix MOSFET 2N-CH 12V 4.5A SC-70-6</p>

### heiße Teile

Mehr

⚙ SIA517DJ-T1-GE3	➡ SIA517DJ-T1-GE3	➡ SIA517DJ-T4-GE3	D SIA519EDJ-T1-GE3	➡ SIA519EDJ-T1-GE3
⊣ SIA533EDJ-T1-GE3	⚙ SIA533EDJ-T1-GE3	D SIA778DJ-T1-GE3	➡ SIA778DJ-T1-GE3	➡ SIA811ADJ-T1-GE3
⚙ SIA811ADJ-T1-GE3	⊣ SIA811DJ-T1	⚙ SIA811DJ-T1-E3	➡ SIA811DJ-T1-E3	➡ SIA811DJ-T1-GE3
D SIA811DJ-T1-GE3	⚙ SIA813DJ-T1-GE3	⊣ SIA813DJ-T1-GE3	⚙ SIA814DJ-T1-GE3	➡ SIA814DJ-T1-GE3
➡ SIA906EDJ-T1-GE3	➡ SIA906EDJ-T1-GE3	⚙ SIA906EDJ-T4-GE3	⊣ SIA907EDJT	➡ SIA907EDJT-T1-GE3
➡ SIA907EDJT-T4-GE3	➡ SIA910EDJ-T1-GE3	D SIA910EDJ-T1-GE3	⚙ SIA911ADJ-T1-GE3	⊣ SIA911ADJ-T1-GE3
⚙ SIA911ADJ-T5-GE3	D SIA911DJ-T1-E3	➡ SIA911DJ-T1-E3	➡ SIA911DJ-T1-GE3	➡ SIA911DJ-T1-GE3
⊣ SIA911DJ-T5-GE3	⚙ SIA911EDJ-T1-GE3	➡ SIA911EDJ-T1-GE3	➡ SIA912DJ	➡ SIA912DJ-T1-GE3
⚙ SIA912DJ-T1-GE3	⊣ SIA913ADJ-T1-GE3	⚙ SIA913ADJ-T1-GE3	D SIA913DJ-T1-GE3	➡ SIA913DJ-T1-GE3
➡ SIA914ADJ-T1-GE3	⚙ SIA914ADJ-T1-GE3	⊣ SIA914DJ-T1-GE3	⚙ SIA914DJ-T1-GE3	➡ SIA915DJ-T1-GE3

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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